





# AMENDMENT UNDER 37 C.F.R. § 1.116(b) EXPEDITED PROCEDURE GROUP 2826 PATENT APPLICATION

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q78644

Yasunori BITO

Appln. No.: 10/720,094

Group Art Unit: 2826

Confirmation No.: 4905

Examiner: Thomas L. Dickey

Filed: November 25, 2003

For:

HETEROJUNCTION FIELD EFFECT TYPE SEMICONDUCTOR DEVICE HAVING

HIGH GATE TURN-ON VOLTAGE AND LOW ON-RESISTANCE AND ITS

MANUFACTURING METHOD

## AMENDMENT UNDER 37 C.F.R. § 1.116(b)

### **MAIL STOP AF**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated December 2, 2005, please amend the aboveidentified application as follows on the accompanying pages.

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